

# Spray Coated Thin Film Barriers for Improved Environmental Durability of Transistors

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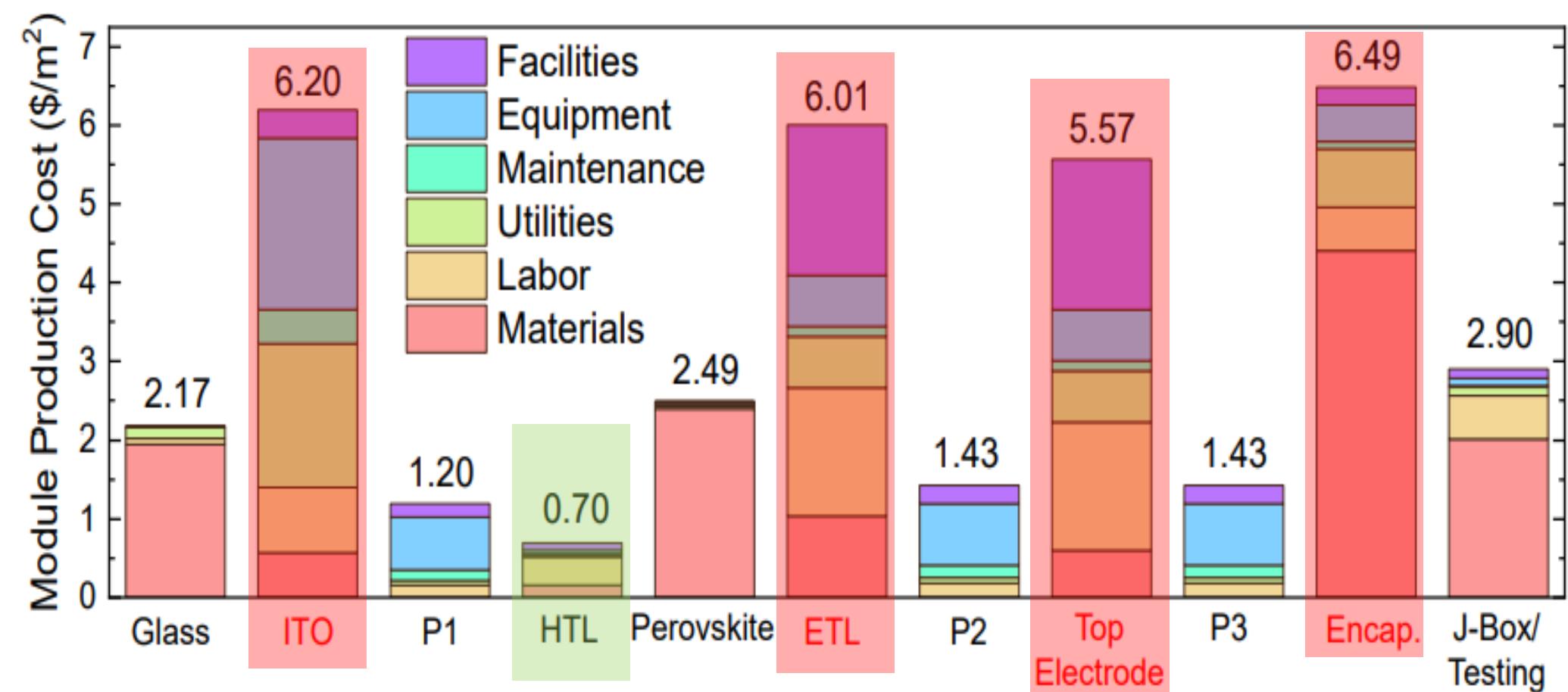
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## Introduction



**Red:** Thin film applications completed under vacuum → \$\$\$

**Green:** Open-air sprayed films → \$

**What is a cost-effective technique to prevent water vapor damage to transistors?**

➤ Aluminum nitrate nonahydrate  $Al(NO_3)_3$  to form an alumina-based thin-film applied with an **open-air spray coater**. The goal is to ensure that transistors exposed to water vapor retain their efficiency rates.

## Transistor Schematic

**Source – Drain** – Measure conductance across the transistor

**Aluminum Oxide** – Barrier coating → Water resistant

**ITO** - Indium Tin Oxide

**Conductivity rates** of bare  $NiO_x$ ,  $ITO \sim 50$  ohms

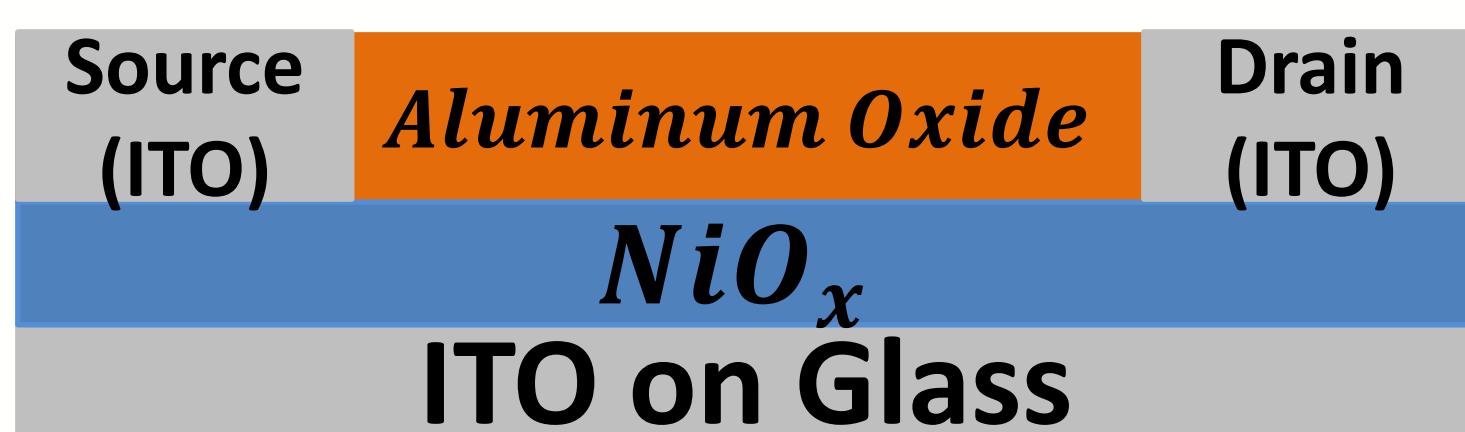
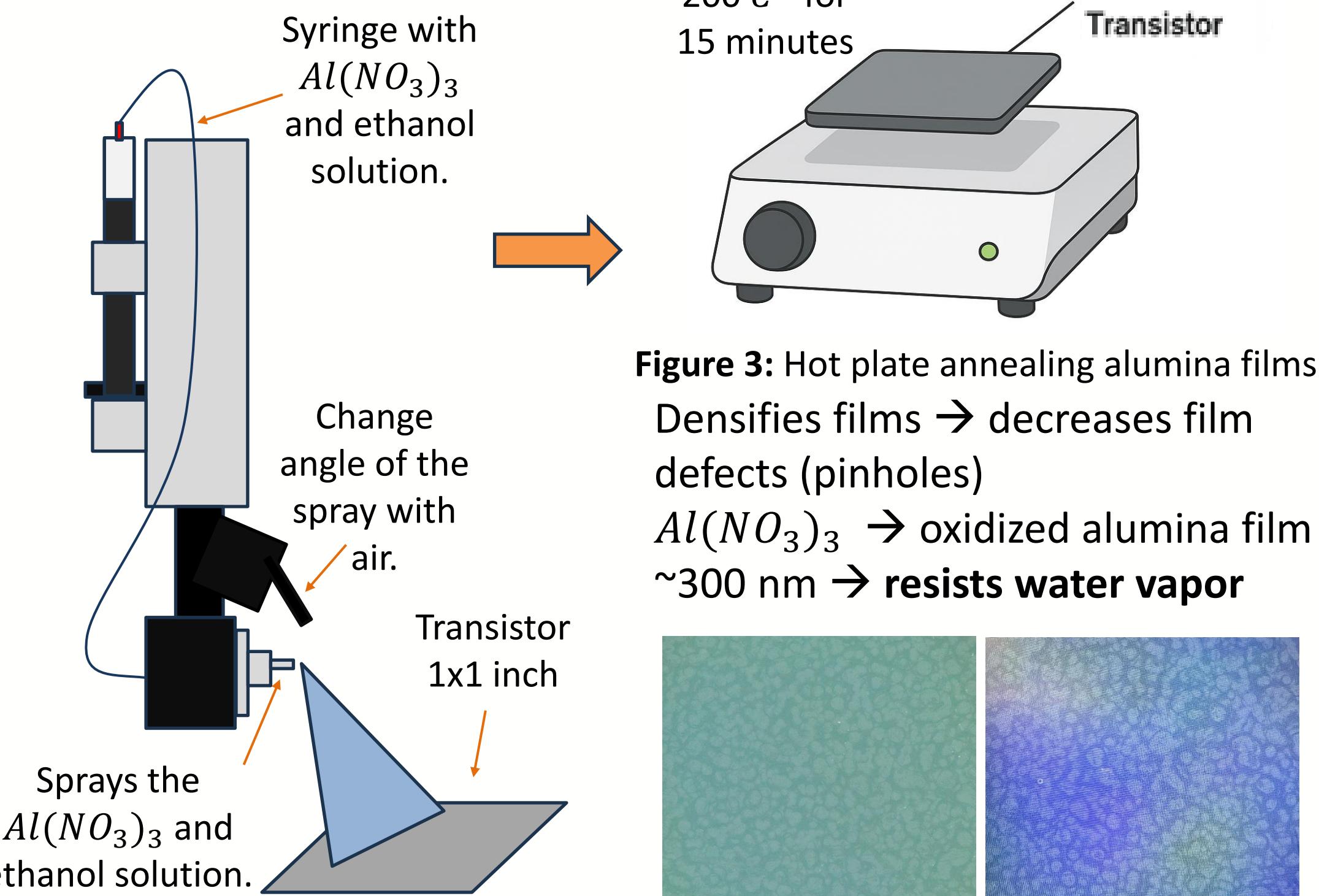


Figure 1: Schematic of transistor with resistive film

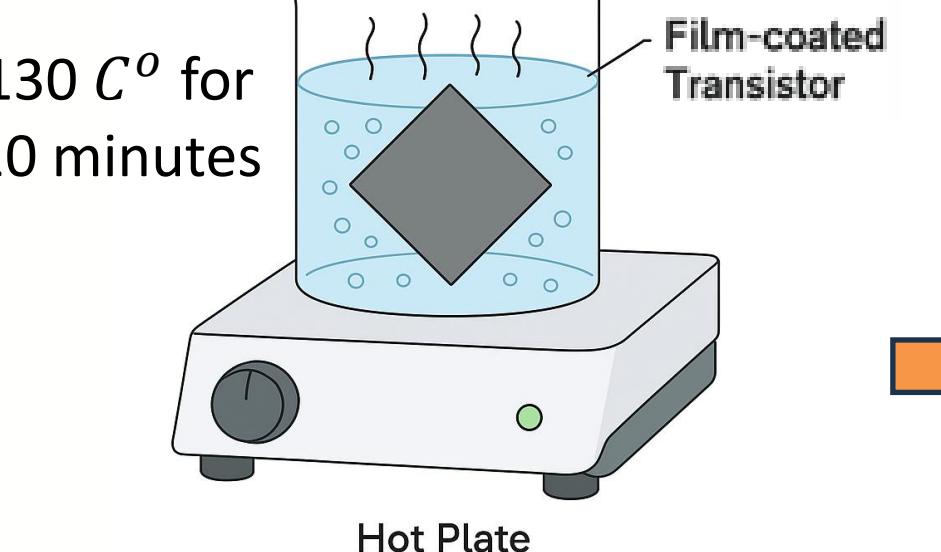
## Methodology

### Open-air spray coater



$Al(NO_3)_3 : 100\text{ g} \rightarrow \$65.70$   
0.37 g  $Al(NO_3)_3 / 10\text{ mL ethanol}$

### Aging



Assess alumina film's protection against transistor degradation

### Annealing

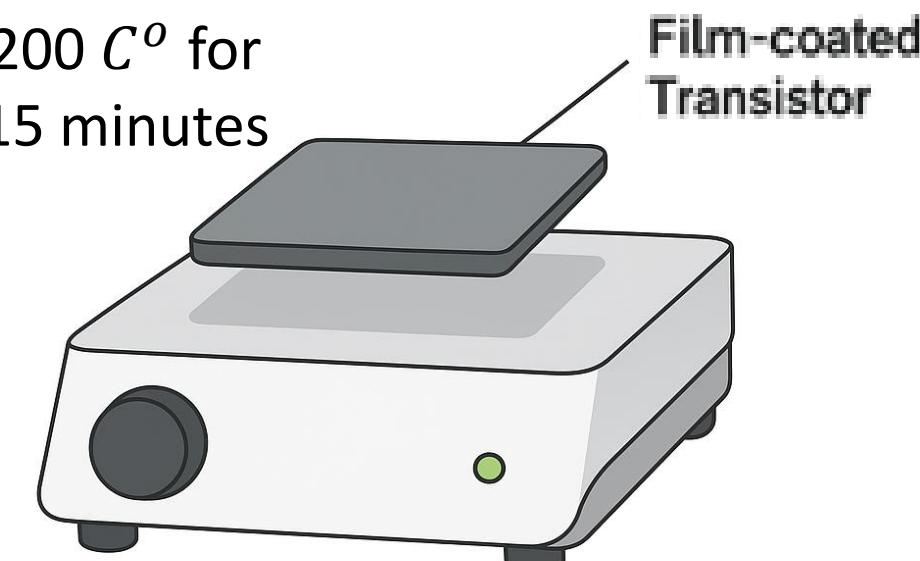


Figure 3: Hot plate annealing alumina films  
Densifies films → decreases film defects (pinholes)  
 $Al(NO_3)_3 \rightarrow$  oxidized alumina film  $\sim 300\text{ nm} \rightarrow$  resists water vapor

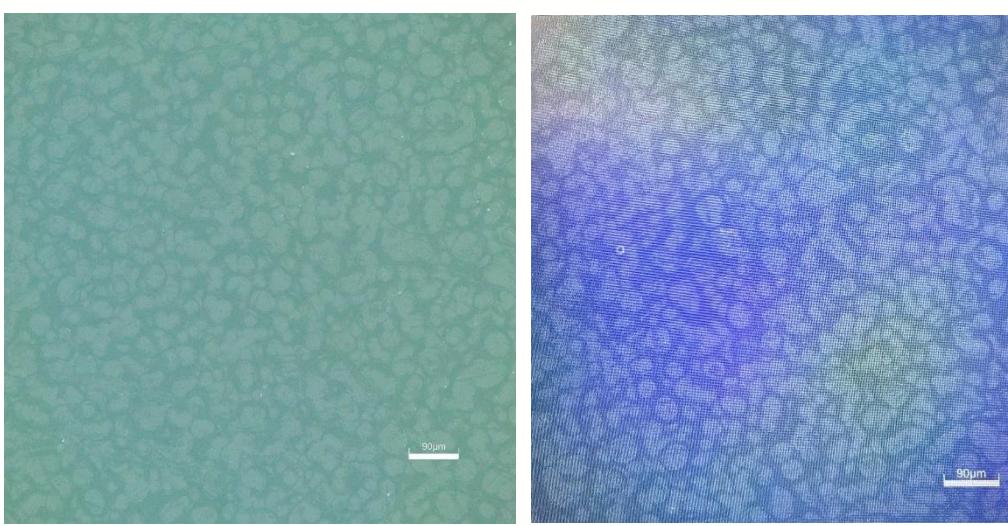
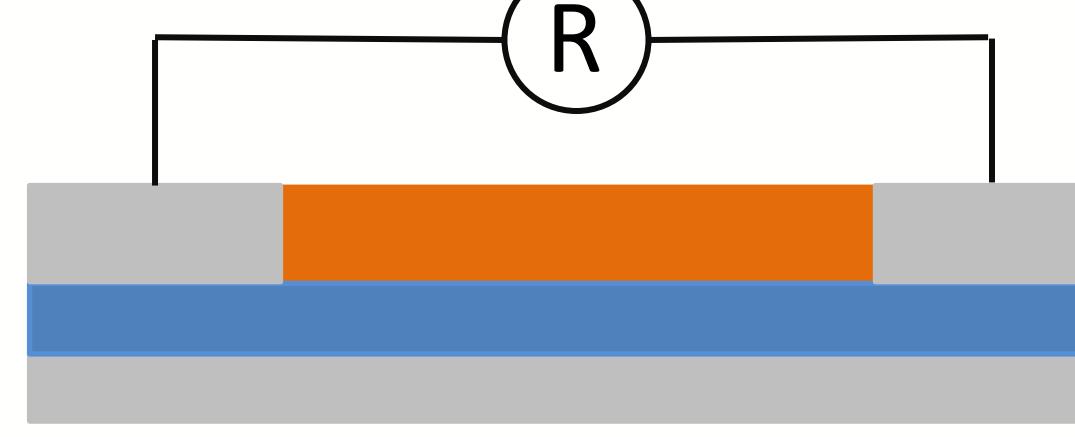


Figure 2: Left- ITO,  $NiO_x$  on glass microscopy image  
Right- ITO on glass,  $NiO_x$  coated with  $Al(NO_3)_3$

### Conduction Testing



Measure conductivity rates of samples before and after aging conditions

## Current Challenges

### Aging of control variable

➤ **Goal:** Degrade conduction rates of two-layer transistor without a protective film.

### Past Testing

- Boil in water 140 mins → no degradation
- Soak in room 20 C° water for ~12 hours → no degradation

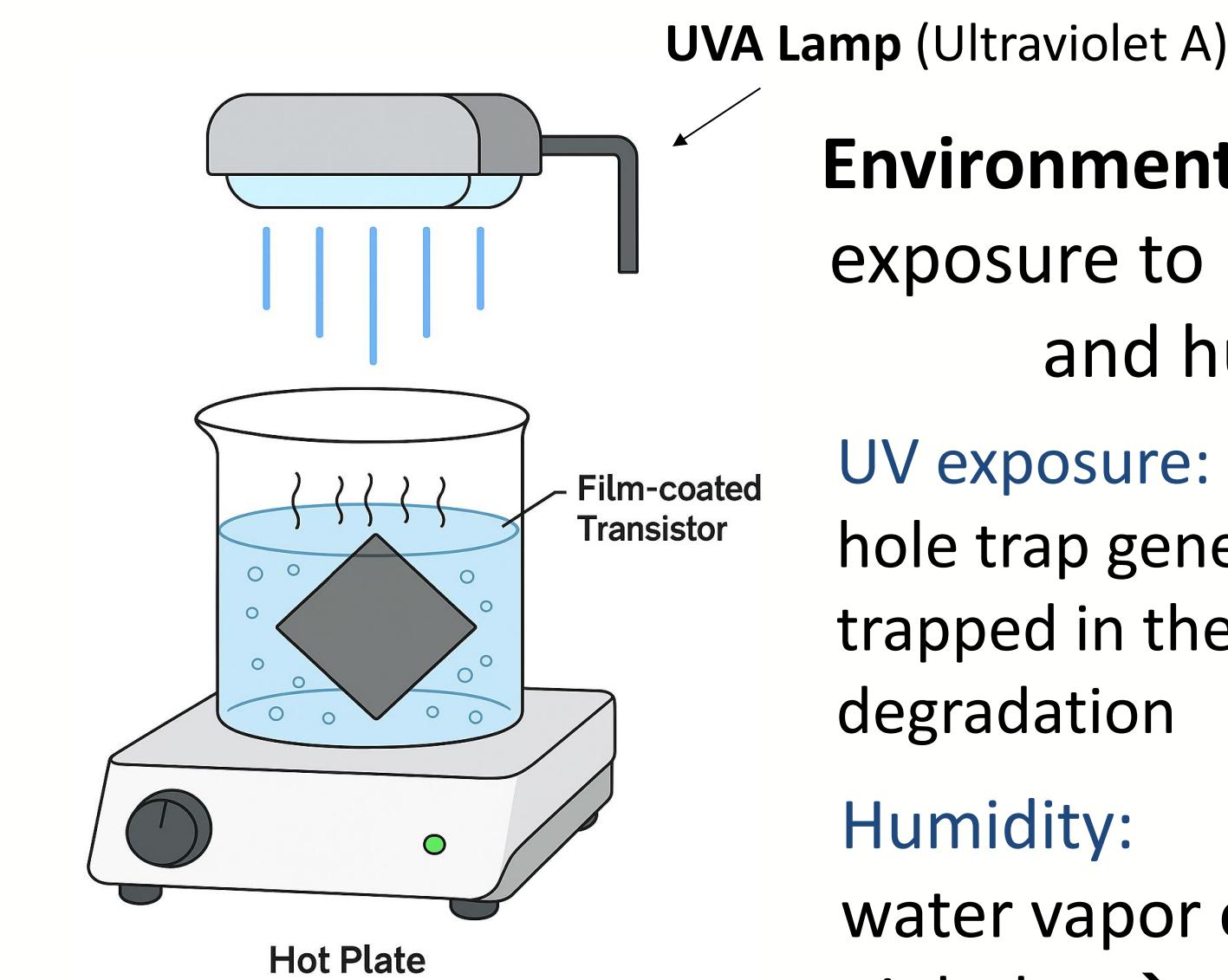
### Future Testing

- Expose samples to UVA and boiling water conditions at the same time

## Future Work

- Measure the conductivity rates before and after UVA aging conditions.

### Aging Thin Film Coated Surface



UVA Lamp (Ultraviolet A)

**Environmental Conditions:** exposure to UVA (sunlight) and humidity

**UV exposure:** hole trap generation → charges trapped in the oxide layer → degradation

**Humidity:** water vapor enters through pinholes → degradation